New Product

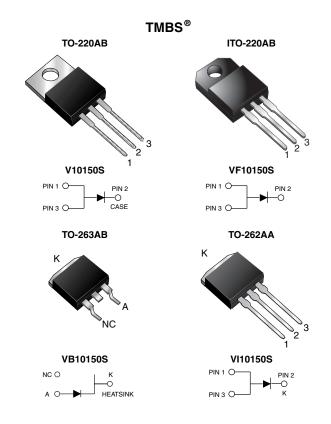


V10150S, VF10150S, VB10150S & VI10150S

Vishay General Semiconductor

High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.59$ V at $I_F = 5$ A



PRIMARY CHARACTERISTICS						
I _{F(AV)}	10 A					
V _{RRM}	150 V					
I _{FSM}	120 A					
V _F at I _F = 10 A	0.69 V					
T _J max.	150 °C					

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation



- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

MECHANICAL DATA

 $\ensuremath{\textit{Case:}}$ TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	V10150S	VF10150S	VB10150S	VI10150S	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	150			V	
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	10				А
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	120				A
Non-repetitive avalanche energy at $T_J = 25$ °C, L = 60 mH	E _{AS}	70				mJ
Peak repetitive reverse current at $t_p = 2 \ \mu s$, 1 kHz, T _J = 38 °C ± 2 °C	I _{RRM}	0.5			A	
Voltage rate of change (rated V _R)	dV/dt	10 000			V/µs	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500		V		
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150				°C

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Breakdown voltage	I _R = 1.0 mA	T _A = 25 °C	V _{BR}	150 (minimum)	-	V		
Instantaneous forward voltage ⁽¹⁾	I _F = 5 A I _F = 10 A	T _A = 25 °C	V	0.79 1.05	- 1.20	v		
	I _F = 5 A I _F = 10 A	T _A = 125 °C	V _F	0.59 0.69	- 0.75			
Reverse current ⁽²⁾	V _R = 100 V	T _A = 25 °C T _A = 125 °C	I	1.3 1.2	-	μA mA		
	V _R = 150 V	T _A = 25 °C T _A = 125 °C	I _R	- 3	150 15	μA mA		

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETERSYMBOLV10150SVF10150SVB10150SVI10150SUNIT							
Typical thermal resistance	$R_{ ext{ heta}JC}$	2.0	4.0	2.0	2.0	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V10150S-E3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VF10150S-E3/4W	1.75	4W	50/tube	Tube			
TO-263AB	VB10150S-E3/4W	1.37	4W	50/tube	Tube			
TO-263AB	VB10150S-E3/8W	1.37	8W	800/reel	Tape and reel			
TO-262AA	VI10150S-E3/4W	1.45	4W	50/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

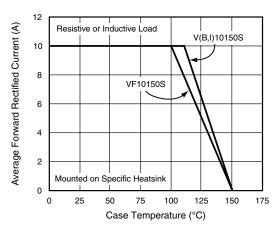


Figure 1. Maximum Forward Current Derating Curve

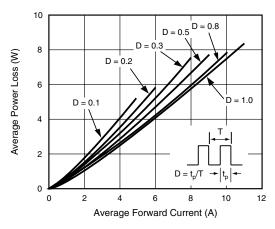


Figure 2. Forward Power Loss Characteristics

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Document Number: 89058 Revision: 24-Jun-09



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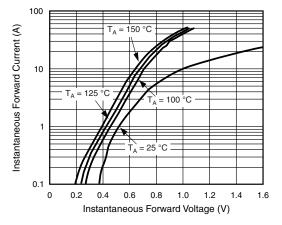


Figure 3. Typical Instantaneous Forward Characteristics

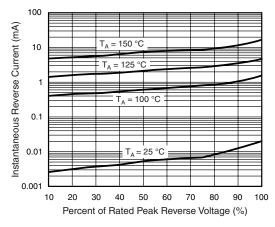


Figure 4. Typical Reverse Characteristics

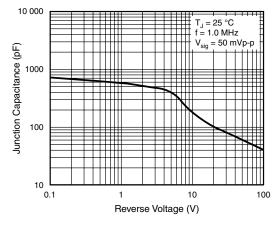


Figure 5. Typical Junction Capacitance

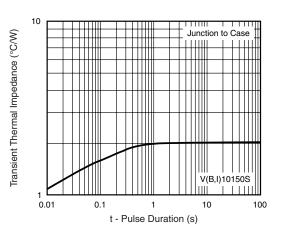


Figure 6. Typical Transient Thermal Impedance

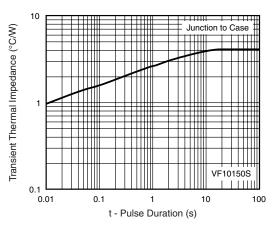
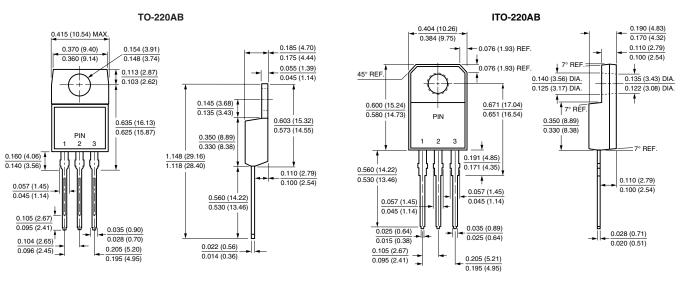


Figure 7. Typical Transient Thermal Impedance

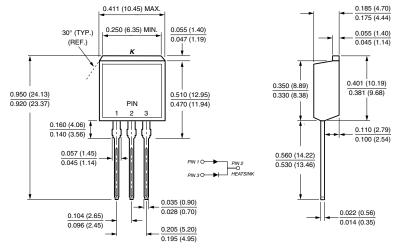
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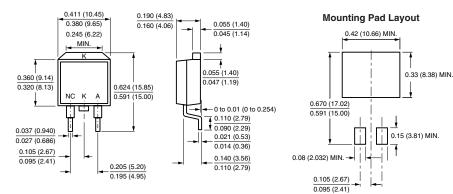
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-262AA



TO-263AB



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